	ypeHits Search Text		DBs	-Time
	RS 33 (polymer with mobility) and 257/40.ccls.		T; US-PGPU	
2	RS 14 (257/40.ccls.) and (poly adj methyl adj methacrylate) RS 0 (257/\$.ccls.) and ((poly adj methyl adj methacrylate) with (gate adj (insulator or insulating or insulation o	USPA	T; US-PGPU	B 2003
3	RS 0 (257/\$ ccls) and ((poly adj methyl adj methacrylate) with (gate adj (insulator or insulating or insulation o	r dielec USPA	T; US-PGPU	B 2003.
4	RS 0 ((poly adj methyl adj methacrylate) same (gate adj (insulator or insulating or insulation or dielectric)))	USPA	T; US-PGPU	
5	RS 0 ((poly adj methyl adj methacrylate) with (gate adj (insulator or insulating or insulation or dielectric)).)		T; US-PGPU	
6	RS::17::((photo or light) adj (responsive or sensitive)) and 257/40 ccls.	USPA	T; US-PGPU	B 2003.
7	RS :17 :("6331356" "6323309" "6271107" "6246105" "6204515" "6159779" "6060338" "5998804" "5908583" "56			
8	RS 2 ((photo or light) adj (responsive or sensitive)) and ((polymer with (gate adj (insulator or insulating or ins	lation USPA	T; US-PGPU	B 2003.
9	RS 26 ((photo or light) adi (responsive or sensitive or sensor or sensing)) and 257/40.ccls.	711004	T; US-PGPU	B 2003.
10	RS 1 "20020084504"		T; US-PGPU	
11	RS 6 ((photo or light) adj (responsive or sensitive or sensor or sensing)) and ((semiconducting or semiconduc	TIVE OF USPA	T. US-PGPU	B 2003.
1	RS 18 ((photo or light) with (responsive or sensitive or sensor or sensing)) and (((semiconducting or semiconducting or semiconducting or semiconducting or semiconducting or semiconducting or semiconducting or semicond	UCIVE USPA	T. US-PGPU	B 2003. B 2003.
100	RS 23 (alcohol with (poly adj vinyl adj phenol)) RS 11 ((photo or light) adj (responsive or sensitive)) and (organic with (fet or (field adj effect adj transistor) or	DSPA	T. US-PGPU	B 2003
1	RS :24 : (polymer with channel) and (organic with (fet or (field adj effect adj transistor) or mosfet or igfet or trans	inter VIICEA	T. US DODU	B 2003
12	RS :1 : ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and			
1000	RS 8 :((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and			
**	RS :28 :((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) sai			
10	RS :14 : ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) sai			
70	RS :2 : ("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) and (((
5.	RS 2 ((*p3ot* or "p3ot* or "p3at" or (alkyl adj thiopene) or octylthiopene or hexylthiopene) with (source or drai	AN LISPA	T: US-PGPU	
33	RS: 1 :((*p3ot* or *p3ot* or *p3at* or (alkyl adj thiopene) or octylthiopene or hexylthiopene) with channel)	LISPA	T: US-PGPU	
33	RS :1 :((*p3ot* or *p3ot* or *p3at* or (alkyl adj thiopene) or octylthiopene or hexylthiopene) same channel)	LISPA	T: US-PGPU	
54	RS 1 ((*p3ot* or *p3ot* or *p3at* or (alkyl adj thiopene) or octylthiopene or hexylthiopene) same channel)	LISPA		
55	RS 0 :((*p3ot* or *p3ot* or *p3at* or (alkyl adj thiopene) or octylthiopene or hexylthiopene) same channel)	FPO:	JPO DERW	ENT: IBM 2003
76	RS 0 (("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or octylthiopene or hexylthiopene) and channel)	FPO		ENT: IBM 2003
77	RS 0 (("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene))and cha	nnel) FPO		ENT: IBM 2003
28	RS 12 (("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene))and cha		T: US-PGPU	
28	RS 0 ((("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) and ch			
30	RS: 0 ((*p3ot* or *p3ot* or *p3at* or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) with tftl		T: US-PGPU	
31	RS 0 (("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) with th		T; US-PGPUI	B 2003/
32	RS 0 (("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) same t	t) USPA	T; US-PGPUI	
33	RS 7 (("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) and tft)	USPA	T; US-PGPUI	B 2003/
34	RS 2 (("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) with (m	osfet o USPA	T; US-PGPUI	B 2003/
	RS 1 (("p3ot" or "p3ot" or "p3at" or (alkyl adi thiopene) or (octyl adi thiopene) or (hexyl adi thiopene)) and ((o	rganic USPA	T; US-PGPUI	B 2003/
36	RS 1 (photo adi transistor) and ((organic adi (mosfet or igfet or fet or transistor or tft or (thin adi film adi trans	istor) o'USPA	T; US-PGPUI	B 2003/
37	RS 1 (photo adi transistor) and (organic with (mosfet or igfet or fet or transistor or titt or (thin adi film adi trans	istor) USPA		
	RS 1 (257/462.ccls.) and (organic with channel)	USPA	T; US-PGPUI	
	RS 2 (257/462.ccls.) and (organic.ab.)	USPA	T: US-PGPUI	B 2003/
T	RS 2 (257/462.ccls.) and (organic.clm.)	USPA	T; US-PGPUI	B 2003/
	RS 11 ("p3ot" or "p3ot" or "p3at" or (alkyl adi thiopene) or (octyl adi thiopene) or (hexyl adi thiopene))and (25	7/462.c¦USPA	T; US-PGPUI	B 2003/
143	RS 6 ((257/\$ ccls) or (438/\$ ccls)) and otft	USPA	T: US-PGPUI	B 2003/

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, Ø C.	Type Hits	Search Text	DB s	Time:Stam:
ŀ⊘p	42 BRS 6	(/257/\$ ccls) or (438/\$ ccls)) and off	USPAT; US-PGPUB	2003/03/26
	43 BRS 2	(organic adj substrate) and (((photo or light or image) adj (responsive or sensitive or sensor or sensing or con	USPAT; US-PGPUB	2003/03/26
-9 F∭	44 BRS 36	(organic with (transistor or fet or mosfet or igfet or misfet) with application with light)	USPAT: US-PGPUB	2003/03/26
÷43 S	45 BRS 8	(photosensing adj (transistor or fet or mosfet or igfet or misfet))	USPAT; US-PGPUB	2003/03/31
3	46 BRS 24	((display adj device) with (photo\$1transistor or (photo adj transistor)))	USPAT; US-PGPUB	2003/03/31
		Adopted Control of the Control of th	USPAT; US-PGPUB	2003/04/01
1 2000		Julia valla and sacosinian.	USPAT; US-PGPUB	2003/04/01
***		Will all allo Matouray.	USPAT: US-PGPUB	2003/04/01
**	50 BRS 12		USPAT: US-PGPUB	2003/04/01
••		((organic adj (tft or thin\$1film or (thin adj film)) adj (mosfet or igfet or transistor or fet or (field adj effect)))) a	USPAT: US-PGPUB	2003/04/01
-•				2003/04/01
-	53 BRS 6	(organic.ti.) and (257/431.ccls.) ((organic.ab.) and (257/431.ccls.)) not ((organic.ti.) and (257/431.ccls.))	HISDAT: HIS DODIN	2003/04/01
	154 BRS 12	((organic ab.) and (257/431 cds.)) not ((organic u.) and (257/431 cds.))	HSPAT: HS-PGPHR	2003/04/01
-3	BRS 17	(organic.ab.) and (257/431.ccls.) (organic.ab.) and (257/462.ccls.)	IISPAT: IIS POPIIR	2003/04/01
	56 BRS 2 57 BRS 1	(organic ab.) and (257/462 cds.)	I ISPAT: I IS-PGPUR	
1 3000	58 BRS 0	(organic ti.) and (257/462 ccls.) ((organic adj. (mosfet or igfet or transistor or fet or (field adj effect) or tft).) and (phototransistor or photo\$1	FPO: JPO: DERWENT: IBA	1 2003/04/01
**	59 BRS 0	((organic adj. (mosfet or igfet or transistor or fet or (field adj effect) or tft))) and ((light or photo) adj (sensin	FPO: JPO: DERWENT: IBN	1 2003/04/01 ···
2	60 BRS 19	((display adj device) with ((light or infrared or radiation or photo)adj (sensing or sensitive or responsive or sens	USPAT: US-PGPUB	2003/04/01
* ₹		(257/462.ccls.) and organic	USPAT: US-PGPUB	2003/04/09
~~	82 BRS 21	(257/462 ccls.) and organic	USPAT: US-PGPUB	2003/04/09
	63 BRS 5	(257/462 ccls.) and organic (photo adi transistor) and (organic with (mos\$1fet or ig\$1fet or mis\$1fet or fet or transistor or tft or (thin adi fil	USPAT: US-PGPUB	2003/04/09
3	164 BRS 6	((photo or light) adj (responsive or sensitive or sensor or sensing)) and ((semiconducting or semiconductive or	USPAT; US-PGPUB	2003/04/09
3	65 BRS 6	((nhoto or light) adj (responsive or sensitive or sensor or sensing)) and ((semiconducting or semiconductive or	USPAT: US-PGPUB	2003/04/09
-4	66 BRS 2	(organic with (mosfet or igfet or transistor or fet or (field adj effect))) and (257/462.ccls.)	USPAT; US-PGPUB	2003/04/09
13 : 70000	67 BRS 2	(organic with (mosfet or igfet or transistor or fet or (field adj effect))) and (257/462.ccls.) (organic with (mosfet or igfet or transistor or fet or (field adj effect))) and (257/462.ccls.)	USPAT; US-PGPUB	2003/04/09
4	68 BRS 7	(display with (photo\$1transistor or (photo adj transistor))) and (257/\$.ccls.) (display with (photo\$1transistor or (photo adj transistor))) and (257/\$.ccls.)	USPAT; US-PGPUB	2003/04/09
* *2	69 BRS 7	(display with (photo\$1transistor or (photo adi transistor))) and (257/\$.ccls.)	USPAT: US-PGPUB	2003/04/09
••	3170∭BRS 10	(organic adi) (mostet or igtet or transistor or tet or (tield adi effect) or ιπ)) — and ((light or infrared or radiation)	USPAT, US-PGPUB	2003/04/09
	71 BRS 3	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ((org	USPAT; US-PGPUB	2003/04/09
- 🛫	72 BRS 11	(organic adj. (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and (sensing or sensitive or resp.	EPO; JPO; DERWENT; IBN	/ 2003/04/09
	73 BRS 11	(organic adj. (mosfet or igfet or transistor or fet or (field adj effect) or tit).) and (sensing or sensitive or resp.	EPO; JPO; DERWENT; IBN	A 2003/04/09
3	74 BRS 5	(photo adj transistor) and (organic with (mos\$1fet or ig\$1fet or mis\$1fet or fet or transistor or tft or (thin adj fil	USPAT, US-PGPUB	2003/04/09 2003/04/09
1 1 30200	75 BRS 5	(photo adj transistor) and (organic with (mos\$1fet or ig\$1fet or mis\$1fet or fet or transistor or tft or (thin adj fil	USPAT US POPUB	
- 3	76 BRS 15	(organic with channel) and (((photo or light or image) adi (responsive or sensitive or sensor or sensing or cond	USPAT, US-PGPUB	2003/04/09
**		((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (orga ((organic adj (mosfet or inject or fet or transistor or tit or (thin adj film adj transistor) or (thin\$1film adj transistor)	USPATI US-PUPUB	2003/04/09
• •2		((organic adj (mostet or igret or let or transistor or itt or (thin adj him adj transistor) or (thins thim adj transistor) ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (orga		2003/04/09
1 2	79 BRS 16 80 BRS 3	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (org ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ((org	ISPAT: US-FGFUB	2003/04/09
-•_		((organic adi (mosfet or infet or fet or transistor or tft or (thin adi film adi transistor) or (thin\$1film adi transistor)		2003/04/09
-€		((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) same (org		2003/04/09
•		polymer and (257/462 ccls.)	USPAT: US-PGPUB	2003/04/09
2				<u>.</u>
*11.0	44 Spicaced tipo #6	Differ from Ab CO. See A Coffice (no. C) Defeate William William Company Wild William		
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	Type Hits	Search Text		DBs	Time
	BRS 0	polymer and (257/462.ccls.)		US-PGPUB	2003/
84	BRS 21	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) same (org	USPAT	US-PGPUB	2003/
85	BRS 4	(organic with (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and (257/431 ccls.)	USPAT	US-PGPUB	2003/
86	BRS 8	polymer and (257/462.ccls.) (organic with (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and (257/431.ccls.)	USPAT	US-PGPUB	2003/
87	BRS 4	(organic with (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and (257/431.ccls.)	USPAT	US-PGPUB	2003/
	ORO ID	foldatile with charmer) and ((buoto or light or linage) and (responsive or sensitive or sensor or sensing or condi-	COLVII	03°F G F G D	2003/
	BRS 12	(("p3ot" or "p3ot" or "p3at" or (alkyl adi thiopene) or (octyl adi thiopene) or (hexyl adi thiopene))and channel)	USPAT	US-PGPUB	2003/
90	BRS 15	(organic with channel) and (((photo or light or image) adi (responsive or sensitive or sensor or sensing or cond	USPAT	US-PGPUB	2003/
91	BRS 26	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (((25.	USPAT	US-PGPUB	2003/
		(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene))and channel)	USPAT	US-PGPUB	2003/
93	BRS 1	*20020084504 *	USPAT	US-PGPUB	2003/
94	BRS 28	*20020084504* ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (((25	USPAT	US-PGPUB	2003/
		(((photo or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)) same (or			2003/
	BRS 16	(((semiconducting or semiconductive or semiconductor) adi polymer) and ((source or drain) with polymer)) and	USPAT	US-PGPUB	2003/
	BRS 21	(((semiconducting or semiconductive or semiconductor) adi polymer) and ((source or drain) with polymer)) and	USPAT	US-PGPUB	2003/
	BRS 2	((organic with pixel) and (257/\$ ccls.)) and (photo\$1transistor or (photo adj transistor)) (organic with (photo\$1transistor or (photo adj transistor))) (organic with (photo\$1transistor or (photo adj transistor))) ((display adj device) with ((light or infrared or radiation or photo)adj (sensing or sensitive or responsive or sens	USPAT	US-PGPUB	2003/
	BRS 13	(organic with (photo\$1transistor or (photo adj transistor)))	USPAT	US-PGPUB	2003/
	BRS 9	(organic with (photo\$1transistor or (photo adj transistor)))	EPO; J	PO; DERWENT; IB	M:2003/
	BRS 5	((display adj device) with ((light or infrared or radiation or photo)adj (sensing or sensitive or responsive or sens	EPO; J	PO: DERWENT: IB	M 2003/
	BKS 4	:"U1259563"	JPO: D	EKYYENI	2003/
		: 5355235 · · · · · · · · · · · · · · · · · · ·	USPAI	US-PGPUB	2003/
		(((photo or light or image) ad (responsive or sensitive or sensor or sensing or detecting or detector)) same (or	USPAI	US-PGPUB	2003/
		(((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) same (or			2003/
		((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (((or			2003/
	BRS 0	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (((or	USPAI	US-PGPUB	2003/
	BRS 39	((((organic or polymer or polymeric) with depletion) and (tft or fet or (field adi effect) or mosfet or igfet or tran	USPAT	US-PGPUB	2003/
	BRS 39	(((organic or polymer or polymeric) with depletion) and (tft or fet or (field adj effect) or mosfet or igfet or tran	USPAT	US-PGPUB	2003/
	BRS 2			US-PGPUB	2003/
	BRS 4	*5232631* and (257/431-466.ccls.) (organic adj active adj layer) and (tft or fet or (field adj effect) or mosfet or igfet or transistor) and (257/431-4	USPAT	US-PGPUB	2003/
	BRS 2	(organic adj active adj layer) and (tri or let) or (let) adj effect) or moster or (greet or transistor) and (25//43)-4	USPAI	US-PGPUB	2003/
	BRS 19	(organic adj. (tft or thin\$1film or (thin adj.film))) and (257/431-466.ccls.)	USPAT	US-PGPUB	2003/
	BRS 0	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (((or ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ((org	USPAT	. 00-2020	2003/
					2003/
	BRS 19 BRS 0	((organic adj. (tft or thin\$1film or (thin adj.film)) and (257/431-466.ccls.)) and (photo or light or image)	LICOAT	LIS DODIE	2003/
	BRS 0	("5892244" "6060333" "6060338") and (257/431-466.ccls.) ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ("589	LICOAT	LIC DODIE	2003/
	BRS 17	(Condition of infall of infalge) and (responsive of sensitive of sensor of sensor of detecting of detector)) and (309)	USPAT.	LIC DODIE	2003/
	BRS 8	"5892244" "6060333" "6060338" "6569707"	USPAI,	US-PGPUB	2003/
		:/#CC 60707#		US-PGPUB	2003/
		(organic adj. (mosfet or igfet or transistor or fet or (field adj. effect) or tit)) and ((light or infrared or radiation			2003/
	BRS 7	(organic adj. (moster of igner of transistor of fer of (field adjeffect) of (fit))—and (fight of finialed of radiation) (organic adj. (semiconductive or semiconducting or semiconductive))—and (257/431-466.ccls.)	USPAT.	LIC DODIE	2003/
	BRS 0	(organic adi depletion) and (257/431-466 ccls.)	USPAI,	US-PGPUB	2003/

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124 BRS 0			US-PGPUB		2003
125 BRS 1	"6303943".PN	USPAT			2003
			: US-PGPUB		2003
		USPAT			2003
128 BRS 3			US-PGPUB		2003
	(((photo\$1voltaic or photo\$1electric or (photo adj (voltaic or electric))) with (misfet or mosfet or infet or transist				2003
	(((photo\$1voltaic or photo\$1electric or (photo adj (voltaic or electric))) with (misfet or mosfet or igfet or transist				2003 2003
131 BRS 12 132 BRS 2	(Unioto of light of image) and (responsive or sensitive or sensor or sensing or detecting or detector)) and (430)		US-PGPUB		2003
133 BRS 8			US-PGPUB		2003
	(organic adjactive) and (438/82,99.ccls.) (organic adj depletion) and (257/431-466.ccls.)				2003
	(organic adj (tft or thin)) and (257/431-466.ccls.)	USPAT	US-PGPIIR		2003
136 BRS 0	(organic adj (tft or ((thin\$1film or (thin adj film)) adj transistor))) and (257/431-466.ccls.)	USPAT	US-PGPUB	2	2003
137 BRS 10	(organic with (tft or ((thin\$1film or (thin adj film)) adj transistor))) and (257/431-466.ccls.)	USPAT:	US-PGPUB	. 2	2003
138 BRS 2	((organic adj (mosfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1film adj transistor	USPAT:	US-PGPUB	2	2003
	(organic adj (mosfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1film adj transistor)				2003
	(organic with (mosfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1film adj transistor				2003
	(organic with (mosfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1film adj transistor				2003
	(organic with (mosfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1film adj transistor				2003
	((257/222.ccls.)) and ((mosfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1film a				2003
			US-PGPUB		2003
	((257/83 ccls.)) and ((mosfet or misfet or light or fet or transistor or tit or (thin adj film adj transistor) or (thin				2003.
	(((257/222 ccls.)) and ((mosfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1 film a				2003
	((optical adj (mosfet or misfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1film ad (US-6060338-\$ or US-6060333-\$ or US-5892244-\$ or US-6512172-\$ or US-5670791-\$ or US-6545290-\$ or US				2003
	((Icd or (liquid adj crystal adj display)) with (drive or driving) with purpose with (tft or thin\$1film\$1transistor or (t				2003
150 BRS 0	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ("656	USPAT.	US-PGPUB		003
151 BRS 25	((US-6060338-\$ or US-6060333-\$ or US-5892244-\$ or US-6512172-\$ or US-5670791-\$ or US-6545290-\$ or	LISPAT	LIS POPUR	2	003
	(optical adj (mosfet or misfet or mesfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thi				003
	(((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) with (tf			2	003
154 BRS 30	((((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector)) adj (fet or misfet				003
155 BRS 3	((((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector)) adj (fet or misfet	USPAT;	US-PGPUB	20	003
156 BRS 37	(US-6512172-\$ or US-6429040-\$ or US-5670791-\$ or US-6197663-\$ or US-6060338-\$ or US-6429450-\$ or U	USPAT;	US-PGPUB	; DERW 20	003
	((((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector)) adj (tft or thin\$1				003
158 BRS 37	(US-6433359-\$ or US-6451415-\$ or US-6452212-\$ or US-6512172-\$ or US-6545290-\$ or US-6433357-\$ or U	USPAT:	US-PGPUB	; DERW 20	
159 BRS 31	(US-6433359-\$ or US-6451415-\$ or US-6452212-\$ or US-6512172-\$ or US-6545290-\$ or US-6433357-\$ or U	USPAT;	US-PGPUB	20	003
	((((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector)) adj (tft or thin\$1				003
	("5596208" ("57962008"	USPAT;	US-PGPUB	20	003
162 BRS 3	(*5596208**	USPAT;	US-PGPUB	20	003
163 BRS 0 164 BRS 17	(p3at with p3ht) and ((257/\$3.cor.) or (438/\$3.cor.)) and (@ad<20011229 or @rlad<20011229)	USPAT;	US-PGPUB		003/
165 BRS 6	(p3at) and ((257/\$3.cor.) or (438/\$3.cor.)) and (@ad<20011229 or @rlad<20011229) ((photo or light or image) adi (responsive or sensitive or sensing or detecting or detector)) and ((p3at), and ((US-PGPUB		003/
agadora u	(turiota of main, or image) and (responsive of sensitive of sensing of perecond of detector)) and (todat), and (t)	DSPAT:	US-PGPUB	~~~~~~~ ` Zl	003/

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	tive or sensing or detecting or detector)) and ((p3at) and	((USPAT; US-PGPUB	2003
166 BRS 1 *20020084504*	***************************************	USPAT; US-PGPUB	2003
167 BRS 0 *2002/0084504*		USPAT; US-PGPUB	2003
168 BRS 14 ("5596208"		USPAT: US-PGPUB	2003
169 BRS 2 ("5596208"	till an annual and datastics as datastics as a second	USPAT; US-PGPUB	2003 2003
170 BRS 23 ((photo or light or image) adj (responsive or sens	tive or sensing or detecting or detector or sensor)) and (na	USPAT; US-PGPUB	2003
1718 BRS 8 ("5331138" 1728 BRS 0 ((photo or light or image) adj (responsive or sens	tive or sensing or detecting or detector or sensor)) and ((* USPAT: US-PGPUB	2003
172 BRS 1 ((photo or light or image) adj (responsive or sens	tive or sensing or detecting or detector or sensor)) and ((p		2003
174 BRS 12 (((photo or light or image) adj (responsive or sens	sitive or sensing or detecting or detector or sensor)) with (d	ri USPAT: US-PGPUB	2003
175 BRS 1 ("0528662" "0575187" "0716459" "0717445	" "0786820" "2360177" 90/08402)	IEPO	2003
	36820" "2360177" 90/08402)	EPO	2003
177 BRS 1 ("528662" "575187" "716459" "717445" "78	36820" "2360177" 90/08402) and ((photo or light or in	a EPO	2003
	36820" "2360177" 90/08402)	DERWENT	2003
	36820" "2360177" 90/08402) and organic	DERWENT	2003
180 BRS 1 ("9008402")		DERWENT	2003
181 BRS 1 6326640.pn.		USPAT; US-PGPUB	2003
	tive or sensing or detecting or detector)) and ((US-643335)	USPAT: US-PGPUB	2003 2003
The state of the s	3.cor.)) and (@ad<20011229 or @rlad<20011229)	EPO: DERWENT	2003
184 BRS : 3 : "9954936" 185 BRS : 0 : ((photo or light or image) adj (responsive or sens	itive or sensing or detecting or detector)) and (66063139.p.	VIISDAT: LIS DODIE	2003
186 BRS 18 ((((photo or light or image) adj (responsive or sens	isitive or sensing or detecting or detector) with (tft or (thin	A HISPAT: HS-PGPHR	2003
187 BRS 1 ((photo or light or image) adj (responsive or sens	tive or sensing or detecting or detector)) and (6603139.pn.) USPAT US-PGPUB	2003
	r.)) and (@ad<20011229 or @rlad<20011229)	USPAT: US-PGPUB	2003
89 BRS 32 ("20010052597"		USPAT: US-PGPUB	2003
190 BRS 0 (p3at or p3ht) and (US-20020190253-A1.DID. and	I (((((photo or light or image) adj (responsive or sensitive o	r USPAT; US-PGPUB	2003
BRS 0 (p3at or p3ht) and ((257/290.cor.) and (@ad<20)	011229 or @rlad<20011229)	USPAT: US-PGPUB	2003
192 BRS 2 (organic with (fet or misfet or mosfet or igfet or m	esfet or (field adj effect) or transistor or tft or thin\$1film\$1tr	a USPAT; US-PGPUB	2003
193 BRS 6 (organic with (fet or misfet or mosfet or igfet or m	esfet or (field adj effect) or transistor or tft or thin\$1film\$1ti	a USPAT; US-PGPUB	2003
194 BRS 3 (organic with (fet or misfet or mosfet or igfet or m	esfet or (field adj effect) or transistor or tft or thin\$1film\$1ti		2003
195 BRS 9 "5693977" and (@ad<20011229 or @rlad<200	(1229) Itive or sensing or detecting or detector)) and (("20010052	USPAT; US-PGPUB	2003
		USPAT: US-PGPUB	2003 2003
197 BRS 8 ((photo or light or image) adi (sensor)) and ((20	010032397 tive or sensing or detecting or detector)) and (6603139 pn.		2003
199 BRS 6 (organic with (fet or misfet or mosfet or igfet or m	esfet or (field adj effect) or transistor or tft or thin\$1film\$1ti	A USPAT: US-PGPUR	2003
	nesfet or (field adj effect) or transistor or tit or thin\$1film\$1		2003
201 BRS 4 ((photo or light or image) adj (responsive or sens	tive or sensing or detecting or detector)) and (("20010052		2003
	\$1responsive or photo\$1sensitive or light\$1sensitive or ima		2003
203 BRS 6 (organic with (fet or misfet or mosfet or igfet or m	esfet or (field adj effect) or transistor or tft or thin\$1film\$1tr	a USPAT; US-PGPUB	2003
	sitive or sensing or detecting or detector or sensor)) with or		2003
	\$ or US-6512172-\$ or US-6545290-\$ or US-6433357-\$ or		2003
206 BRS 31 ("20030038590"	•	USPAT: US-PGPUB	2003
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	Type Hits	Search Text		DBs	Time
206	BRS 31	("20030038590"	USPAT;	US-PGPUB	2003/1
207	BRS 30	(((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor)) with org	USPAT;	US-PGPUB	2003/1
208	BRS 2	"9925028"	DERWE	NT	2003/1
	BRS 2	*9925028*	DERWE	NT	2003/1
210	BRS 27	polyparaphenylenevinylene with organic	USPAT;	US-PGPUB	2003/1
	BRS 3	"20010052597"	USPAT;	US-PGPUB	2003/1
216	BRS 5	20010052597" ((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor)) and (("2")	USPAT:	US-PGPUB	2003/1
213	BRS 1	: "20020057398" and (transistor or tft)	USPAT,	US-PGPUB	2003/1
11214	® BRS 5	: ((photo or light or image) adi (responsive or sensitive or sensing or detecting or detector or sensor)) and (("2"	USPAT:	US-PGPUB	2003/1
215	BRS 15	(((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor)) and ((*2	USPAT:	US-PGPUB	2003/1
11746	BRS 1	*20020084504* and (high adi dielectric)	USPAT:	US-PGPUB	2003/1
747	BRS 15	((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor)) and ((2	USPAT:	US-PGPUB	2003/1
1548	BRS 28	(p3ht)	USPAT:	US-PGPUB	2003/1
	BRS 3	(p3ht) with light	USPAT:	US-PGPUB	2003/1
1 337	BRS 2	(p3ht)and ("20020017612" "6303943").did.	USPAT:	US-PGPUB	2003/1
55	BRS 1			US-PGPUB	2003/1
22	BRS 0	poly\$1*3-hexyl thiophene" with mobility	USPAT	US-PGPUB	2003/1
	BRS 6	p3ht with mobility	USPAT	US-PGPUB	2003/1
	BRS 3	(poly adj hexylthiophene)	LISPAT.	US-PGPUB	2003/1
	BRS 27	(gold with transparent with "100 nm")	LISPAT.		2003/1
	BRS 1	glass and (6197663.pn.)	LISPAT	LIO DODLID	2003/1
		(p3ht with acceptor)			2003/1
	BRS 2	() point with account	LICDAT.	US-PGPUB	2003/1
55	BRS 14	(p3ht with doped) ((glass adj substrate) with polyimide) and tft and (257/\$3.cor.)	LICDAT.	LIA BABLIB	2003/1
	BRS 26	polyimide with transparent with micron	LICDAT.	LIC DODLID	2003/1
	BRS 1	(polyimide with transparent with nm) and ((257/\$3.cor.) or (438/\$3.cor.))	LICDAT.	US-PGPUB	2003/1
	BRS 35	polyimide with transparent with nm not wavelength	LICDAT.	US-PGPUB	2003/1
		((pmma) with (gate adj (dielectric or insulator or insulating or insulation)))	EDO: I	OO-FORDERT IDM	
	BRS 1	((prima) with (gate adj (detectric or insulator or insulating or insulation))) (mylar with flexible) and ((257/\$3.cor.) or (438/\$3.cor.))	LEDAT	US DODUB	2003/1
	BRS 3	((nolymethyl adj methacrylate) with (gate adj (dielectric or insulator or insulating or insulation))	HEDAT	US-PGPUB	2003/1
	BRS 1			US-PGPUB	2003/1
					2003/1
		((polymethyl adj methacrylate) with (gate))	EDO: D	CONCENT	2003/1
	BRS 8	"9803087"	EPO, D	ERWENT	
	BRS 0	"qb9803087"	EPO, DI	ERWENI	2003/1
	BRS 0	9721808.5	EPO, DI	ERWENT	2003/1
	BRS 0			ERWENT	2003/1
	BRS 0	909/218085			2003/1
	BRS 1	.*gb09721808"	EPO; U		2003/1
	BRS 0	GB002330451	EPO; U	ERWENT	2003/1
	BRS 0				2003/1
1144	BRS 3	"2330451" (((oolvmethyl adi methacrylate) with (gate))) and ((257/\$3 cor.) or (438/\$3.cor.))	EPO: DI	ERWENT	2003/1
(1/4/	BRS 6	((100)\methyl adi methacrylate) with (date))) and ((25//\$3 cor.) or (438/\$3.cor.))	USPAT:	US-PGPUB	2003/1

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247 BRS 6	(((polymethyl adi methacrylate) with (gate))) and ((257/\$3.cor.) or (438/\$3.cor.))		US-PGPUB	2003
248 BRS 0	(polyimide with (dielectric adj constant)) and ((257/\$3.cor.) or (438/\$3.cor.)) and (@ad<20011229 or @rlad<2	USPAT	US-PGPUB	2003.
249 BRS 25	(noblimide with (dielectric adj constant)) and ((257/\$3 cor.) or (438/\$3 cor.)) and (@ad<20011229 or @dad<	USPAT	: US-PGPUB	2003
250 BRS 1	6480577.pn. and polyimide ((pmma) with (gate adj (dielectric or insulator or insulating or insulation))) ((alcohol) same (gate adj (dielectric or insulator or insulating or insulation))) and (nobodny) with alcohol)	USPAT	US-PGPUB	2003
251 BRS 7	((pmma) with (gate adj (dielectric or insulator or insulating or insulation)))	USPAT	; US-PGPUB	2003
252 BRS 6	- Aldicolol) Salife (date adj (diciectile of misdiator of misdiation)) / and (pory and misdiator)		,	2003
253 BRS 4	:/(alcohol) with (gate adj (dielectric or insulator or insulating or insulation))) and (polyviny) with alcohol)	USPAT	: US-PGPUB	2003
254 BRS 2	((pva) with (gate adi (dielectric or insulator or insulating or insulation))) ((pva) with (gate adi (dielectric or insulator or insulating or insulation)))	USPAT	; US-PGPUB	2003
255 BRS 3	((pva) with (gate adi (dielectric or insulator or insulating or insulation)))	EPO; J	PO: DERWEN	T: IBM 2003
256 BRS 5	(polymer with (gate adj (dielectric or insulator or insulating or insulation))) same (polymer with (pva or alcohol)	USPAI	US-PGPUB	2003
257 BRS 16) ((polymer with (gate adj (dielectric or insulator or insulating or insulation))) and (polymer with (pva or alcohol))	USPAT	; US-PGPUB	2003
258 BRS 10) if (polymer with (gate adj (dielectric or insulator or insulating or insulation))) and (polymer with (pmma))) and (USPAT	; US-PGPUB	2003
			; US-PGPUB	2003
260 BRS 0	((polymer with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20011229)) and (pmma	USPAT	; US-PGPUB	2003
261 BRS 0	((polymer with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20011229)) and ((pva o	USPAT	; US-PGPUB	2003
262 BRS 4	((polymer with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20011229)) and ((pva o			2003
263 BRS 19	e ((pva or alcohol or pmma) with tft) and (@ad<20011229)	USPAT	; US-PGPUB	2003
264 BRS 2	((photo adj resist) with (gate adj (dielectric or insulator or insulating or insulation)) not (cover or covered or re			2003
265 BRS 0	(((poly\$1vinyl)) with tft.) and (@ad<20011229)	USPAI	; US-PGPUB	2003
266 BRS 6	: (((poly adj vinyl)) with tft) and (@ad<20011229) :((poly adj vinyl) with (gate adj (dielectric or insulator or insulating or insulation)) not (cover or covered or remo	USPAT	; US-PGPUB	2003
267 BRS 0	((poly adj viny)) with (gate adj (dielectric or insulator or insulating or insulation)) not (cover or covered or remo	USPAI	; US-PGPUB	2003
268 BRS 2			; US-PGPUB	2003
	3 ((poly adj vinyl) with gate) and (@ad<20011229)	USPAT	US-PGPUB	2003
270 BKS 22		USPAI	US-PGPUB	2003
271 BRS 5	1.4.4.4.4.4.4.4.4.4.4.4.4.4.4.4.4.4.4.4		US-PGPUB	2003
	3 ("4021835"	USPAI	US-PGPUB	2003
	(('4021835'	USPAI	US-PGPUB	2003
274 BRS 2	((poly\$1vinyl) with gate) and (@ad<20011229) and (257/40.ccls.)	USPAI	US-PGPUB	2003
215 BKS 15) ((poly\$1vinyl) adj alcohol) and (@ad<20011229) and (257/40.ccls.)	USPAI	, US-PGPUB	2003
210 BRS 38			US-PGPUB	2003
211 BRS 15			US-PGPUB	2003 2003
				2003
279 BRS 1		LICOAT	US-PGPUB	2003
AND DEC 4	2 (organic_with (glass adi resin)) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.)) 3 (inorganic with (gate adi (dielectric or insulator or insulating or insulation))) and (@ad<20010102) and (257/4			2003
282 BRS 35				2003
283 BRS 0	(inorganic with (dielectric or insulator or insulating or insulation)) with easier) and (@ad<20010102) and ((257/			2003
284 BRS 5	(inorganic with (dielectric of insulator of insulating of insulation) with easier) and (@au-20010102) and ((257) (inorganic adjigate) and (@ad<20010102) and ((257)\$3.cor.) or (438/\$3.cor.)) and tft	LICDAT	LIS DODIE	2003
285 BRS 8	(inorganic adjigate) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))	LISPAT	· LIS_PGPLIR	2002
288 BRS 10	(1) (inorganic with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20010102) and ((257/	LISPAT	· LIS-PGPLIR	
287 BRS 0	((silicon adj dioxide) with (gate adj (dielectric or insulator or insulating or insulation)) with simple) and (@ad<2	LISPAT	LIS-PGPUR	2003
288 BRS 0	(silicon add dioxide) with (gate add (dielectric or insulator or insulation) with cheap) and (@ad)</td <td></td> <td></td> <td>2003</td>			2003

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288 BRS 0	((silicon adi dioxide) with (gate adi (dielectric or insulator or insulating or insulation)) with cheap) and (@ad<2	USPAT	US-PGPUB	2003/
	((silicon adi dioxide) with (gate adi (dielectric or insulator or insulating or insulation)) with cost) and (@ad<20	USPAT	US-PGPUB	2003/
	((silicon adi dioxide) with (gate adi (dielectric or insulator or insulating or insulation)) with ease) and (@ad≺20			2003/
	((silicon adj dioxide) with (gate adj (dielectric or insulator or insulating or insulation)) with simpler) and (@ad<			2003/
	(("sio.sub.2") with (gate adj (dielectric or insulator or insulating or insulation)) with simpler) and (@ad<20010			2003/
	((*sio.sub.2*) with (gate adj (dielectric or insulator or insulating or insulation)) with cost) and (@ad<20010102			2003/
	(inorganic with (dielectric or insulator or insulating or insulation) with property) and (@ad<20010102) and ((2 finorganic with (dielectric or insulator or insulating or insulation) with simpler) and (@ad<20010102) and ((25			2003/
295 BRS 0 296 BRS 0	(Inorganic with (dietectric or insulator or insulating or insulation) with simple() and (@ad<20010102) and ((25	LICOAT	US-PGPUB	2003/
297 BRS 19	(((poly\$1vinyl) adj alcohol) with tft) and (@ad<20011229) (buckminsterfullerene) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))	LICOAT	LIS POPUB	2003/
298 BRS 1	(buckministerfullerene yand (wad<20010102) and ((237)33.com) of (436/\$3.com) (buckminsterfullerene with (acceptor)) and (@ad<20010102) and tit	LISPAT	LIS-PGPLIB	2003/
299 BRS 7	(buckminsterfullerene with (acceptor)) and (@ad<20010102) and the	USPAT	US-PGPUR	2003/
300 BRS 10	(channel with (acceptor) with greater) and (@ad<20010102)	USPAT	US-PGPUB	2003/
301 BRS 30	(channel with (acceptor) with more) and (@ad<20010102)	USPAT	US-PGPUB	2003/
302 BRS 24	(channel with (acceptor)) and (@ad<20010102) and tft	USPAT	US-PGPUB	2003/
	(buckminsterfullerene) and (@ad<20010102) and (257/40 ccls)	USPAT	US-PGPUB	2003/
304 BRS 2	(buckminsterfullerene same channel) and (@ad<20010102)	USPAT	US-PGPUB	2003/
	((titanium adi dioxide) or tio.sub.2) with acceptor) and ((Qad~20010102) and ((257/\$5.cor.) or (456/\$5.cor.	USPAI	US-PGPUB	2003/
	((titanium adi dioxide) or "tio.sub.2") with current) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))			2003/
	(part)) ((part) (part) (part) (part) (part) (part) (part) (part)			2003/
	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) with poly			2003/
309 BRS 0			US-PGPUB	2003/
310 BRS 0	(buckminsterfullerene) and ((((photo or light or image) adj (responsive or sensitive or sensor or sensing or de	USPAT	US-PGPUB	2003/
311 BRS 0 ((photo or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)) and (@ad			2003/
312 BRS 19 (US-PGPUB	2003/
	(photo adj (fet or transistor)) and (@ad<20010102) and ((257/53.cor.) or (438/\$3.cor.))) and (sensitivity with			2003/ 2003/
314 BRS 0 (315 BRS 0 (photo adi (fet or transistor)) and (@ad<20010102) and (257/40.cor.)	USPAT.	LIC DODUB	2003/
316 BRS 5 ((light adj sensitive) with (fet or transistor)) and (@ad<20010102) and (257/40.cor.) (photo adj (fet or transistor)) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))) and (sensitivity with	LICDAT	US-FGFUB	2003/
	((light adj sensitive) with (fet or transistor)) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))) and (sensitivity with			2003/
	((light adj sensitive) with (fet or transistor)) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))) and (s			2003/
319 BRS 17 ((photo adi (fet or transistor)) with sensitivity) and (@ad<20010102) and ((257/\$3 cor.) or (438/\$3 cor.))	USPAT	US-PGPUB	2003/
320 BRS 9	poly\$1"3-hexylthiophene"	USPAT	US-PGPUB	2003/
321 BRS 2 (poly\$1"3-hexylthiophene" ("p3ot" or "p3ot" or "p3at") with (source or drain))	USPAT	US-PGPUB	2003/
#322 BRS 2 (("p3ot" or "p3ot") with (source or drain))		US-PGPUB	2003/
#323⊗BRS :0 :	(p3ot with light) and (@ad<20010102)	USPAT:	US-PGPUB	2003/
324 BRS 3	(p3ot same light) and (@ad<20010102)		US-PGPUB	2003/
			US-PGPUB	2003/
326 BRS 0	(p3ot and light) and (@ad<20010102) poly\$1"3-octythiophene" and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))		US-PGPUB	2003/
327 BRS 18 ((light adj sensor) with sensitivity) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))		US-PGPUB	2003/
328 BRS 9 (US-PGPUB	2003/
329 BRS 6 (polv adi "3-octvithiophene") and (@ad<20010102)	EPO: JI	PO: DERWENT: IB	M:2003/

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		(poly adj "3-octylthiophene") and (@ad<20010102)	EPO; JI	PO: DERWEN	T: IBM 2003/11
	30 BRS 2	p3ot and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.)) ((("3-octylthiophene") and (@ad<20010102)) and semiconductor) not (((poly adj "3-octylthiophene") and (@	USPAT;	US-PGPUB	2003/11
	31 BRS 5	((("3-octylthiophene") and (@ad<20010102)) and semiconductor) not (((poly adj "3-octylthiophene") and (@	USPAT	US-PGPUB	2003/11
	32 BRS 0				T: IBM 2003/11
	33 BRS 1	"6331356" and transducer		US-PGPUB	2003/11
A 77. 18 Trees	34 BRS 0	:"6331356" and octylthiopene	USPAT;	US-PGPUB	2003/11
	35 BRS 1	"6331356" and octylthiophene (((("octylthiophene") and (@ad<20010102)) and semiconductor) not (((("3-octylthiophene") and (@ad<2001	USPAT;	US-PGPUB	2003/11
	BRS 6	((("octylthiophene") and ((() and <20010102)) and semiconductor) not (((("3-octylthiophene") and ((() ad<2001	USPAT	US-PGPUB	2003/11
	37 BRS 21	(sensor and octylthiophene) and (@ad<20010102) ((sensor and octylthiophene) and (@ad<20010102)) not (((("octylthiophene") and (@ad<20010102)) and se	USPAT	US-PGPUB	
	38 BRS 6	((Cad<20010102)) and se	USPAL	US-PGPUB US-PGPUB	2003/11
(<u> </u>	23 DRO 32	sensor and octythiophene (257/40.ccls.) and octythiophene	LICOAT	LIA DADILIA	.0000144
	## DDC 10	(257/40.ccis.) and octylinopherie (257/40.ccis.) and octy\$1thiopherie			
	2 BRS 0	((257/40.ccls.) and octy\$1thiophene) not ((257/40.ccls.) and octytthiophene)	LICOAT	LIS DODLIB	2003/11
	43 BRS 8	((257/40.ccis.) and (thiophene same octyl)	LISPAT	LIS DODLIR	
A 100	44 BRS 6	((257/\$3.cor.) or (438/\$3.cor.)) and (thiophene same octyl)	LISPAT.		
		(257/40.ccls.) and octyl\$1thiophene	LISPAT	LIC BOBLIE	2000144
	6 BRS 1	((257/\$3.cor.) or (438/\$3.cor.)) and poly\$1octy/\$1thiophene	LISPAT		2003/11
	BRS 1	((257/\$3.cor.) or (438/\$3.cor.)) and poly adj octyl adj thiophene	USPAT	US-PGPUB	2003/11
	48 BRS 1	((257/\$3.cor.) or (438/\$3.cor.)) and (poly adj octyl adj thiophene)	USPAT	US-PGPUB	2003/11
		((257/\$3.cor.) or (438/\$3.cor.)) and (octyl adi thiophene)	USPAT	US-PGPUB	2003/11
	50 BRS 2	((428/\$3.cor.)) and (octyl adj thiophene)	USPAT:	US-PGPUB	2003/11
	51 BRS 0	((427/\$3.cor.)) and (octyl adj thiophene)	USPAT:	US-PGPUB	2003/11
3	52 BRS 5	(sensor) and (octyl adi thiophene)	USPAT:	US-PGPUB	2003/11
3	53 BRS 2	((257/\$3.cor.) or (438/\$3.cor.)) and p30t	USPAT:	LIO DODLID	2003/11
	4 BRS 5	(sensor) and p30t	USPAT:	US-PGPUB	2003/11
	BRS 3	(transistor) and p30t	USPAT:	US-PGPUB	2003/11
3	6 BRS 3	(transistor) and p\$1"30t"	USPAT:	US-PGPUB	2003/11
	57 BRS 0	(transistor) and pol\$1"3-octylthiophene"	USPAT;	US-PGPUB	2003/11
	58 BRS 0	(transistor) and pol\$1"3-octylthiophene" (transistor) and poly\$1"3-octylthiophene"	USPAT:	US-PGPUB	2003/11
	BRS 6	: poly\$1"3-octylthiophene"	USPAT;	US-PGPUB	2003/11
	60 BRS 7	((organic with (misfet or mosfet or igfet or fet or transistor)) and thiophene) and (@ad<20010102) and octyl			2003/11
	BRS 0	(((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconduc			2003/11
· 1120		(((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not (((organic with (misfet or			2003/11
	63 BRS 2	((US-4862237-\$ or US-6452212-\$ or US-6433359-\$ or US-6326640-\$ or US-5329112-\$ or US-5892244-\$ or			
	64 BRS 3	((US-4862237-\$ or US-6452212-\$ or US-6433359-\$ or US-6326640-\$ or US-5329112-\$ or US-5892244-\$ or			
		("4021835"	USPAT;	US-PGPUB	2003/11
ા!#	36 BRS 7	("4021835" ("3-octylthiophene" and (misfet or mosfet or igfet or fet or transistor)) and (@ad<20010102)	USPAT;	US-PGPUB	2003/11
15	56 BRS 1		USPAT	US-PGPUB	2003/11
2	DD DDC 12	5315129.pn.		US-PGPUB	2003/11 T: IBM 2003/11
3	MADE 10			US-PGPUB	1; IBM 2003/11 2003/11

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Type Hits		DBs	Time
370 BRS 20	"3-octyithiophene" and (misfet or mosfet or igfet or fet or transistor)	USPAT: US-PGPUB	2003/
371 BRS 0	"poly(3-octylthiophene)" and (misfet or mosfet or igfet or fet or transistor)		2003
372 BRS 19	"poly (3-octylthiophene)" and (misfet or mosfet or igfet or fet or transistor)	LISPAT: LIS DOPLIR	2003/
373 BRS 8	"poly (3-octylthiophene)" and (photo\$1sensitive or photo\$1sensitivity)	LISDAT: LIS DODLIR	2003/
	"3-octylthiophene" and (photo\$1sensitive or photo\$1sensitivity)	USPAT: US-PGPUB	2003
1114 DRS 10	"3-octythiophene" and (photo\$1sensitive or photo\$1sensitivity) ((organic with (photo\$1transistor or (photo adi transistor)))) and ((@ad<20010102) or (@rlad<20010102))	LISPAT: LIS-POPLIA	2003/
1375 DDC 37	(Congride came (photos thransistor or (photo adi transistor)))	USPAT; US-PGPUB	
1977 DRG 0	(organic same (photo\$1transistor or (photo adj transistor))) (((organic same (photo\$1transistor or (photo adj transistor)))) and ((@ad<20010102) or (@rlad<20010102)	LISDAT: LIS DODLIR	2003/
1930 BBS 6	"n3at" and (nhoto\$1eenstine or photo\$1eenstinity)	USPAT; US-PGPUB	2003/
1070 BPS 20	*p3ot* and (photo\$1sensitive or photo\$1sensitivity) ((organic same (photo\$1transistor or (photo adi transistor)))) and ((@ad<20010102) or (@rlad<20010102))	LISPAT: LIS-PGPUR	2003/
380 BRS 1	(A) to Stransistor or (A) hoto adi transistori) and "Coctythiophene"	LISPAT: LIS-PGPUR	2003/
381 BRS 9	(photo\$1transistor or (photo adi transistor)) and "3-octylthiophene" ("3-octylthiophene" and (photo\$1sensitive or photo\$1sensitivity)) and ((@ad<20010102) or (@rlad<2001010	USPAT: US-PGPUR	2003/
1393 BRS 36	"alloythinghene" and (photo\$1sensitive or photo\$1sensitivity)	LISPAT: LIS-PGPLIR	2003/
1393 BRS 0	alkytthiophene" and (photo\$1sensitive or photo\$1sensitivty) (photo\$1transistor or (photo adi transistor)) and (("alkythiophene" and (photo\$1sensitive or photo\$1sensitivi	LISPAT: LIS-PGPLIR	2003/
384 BRS 0	'alky/thiophene' same (photo\$1sensitive or photo\$1sensitivity)	LISPAT: LIS-PGPLIR	2003/
385 BRS 3	((((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not (((organic with (misfet or	USPAT: US-PGPUB	2003/
	("alkylthiophene" and (photo\$1sensitive or photo\$1sensitivity)) and ((@ad<20010102) or (@rlad<20010102)		2003/
	(((misfet or mosfet or igfet or fet or transistor) and alkylthiophene) and ((@ad<20010102) or (@rlad<20010		2003/
388 BRS 16	((((misfet or mosfet or igfet or fet or transistor) and alkylthiophene) and ((@ad<20010102) or (@rlad<20010	USPAT US-PGPUB	2003/
389 BRS 15	(organic with (photo\$1transistor or (photo adj transistor))	USPAT: US-PGPUB	2003/
390 BRS 6	(((((@ad<20010102)) or (@rlad<20010102)) and (array with (position or motion))) and ((photo\$1transistor or	USPAT: US-PGPUB	2003/
391 BRS 36	(((@ad<20010102) or (@rlad<20010102)) and (array with (photo\$1transistor or (photo adj transistor)))) and	USPAT US-PGPUB	2003/
392 BRS 1	*20020084504* and position	USPAT: US-PGPUB	2003/
393 BRS 17	*20020084504* and position ((((@ad<20010102)) or (@rlad<20010102)) and (array with (photo\$1transistor or (photo adi transistor)))) and (@ad<20010102) or (@rlad<20010102) and ((photo\$1transistor) or (photo adi transistor)) with (concert or a	USPAT: US-PGPUB	2003/
394 BRS 21	(@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with (sensor or se	USPAT: US-PGPUB	2003/
	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adi transistor)) with beam)) and		2003/
	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	USPAT: US-PGPUB	2003/
	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and		2003/
398 BRS 13	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	USPAT; US-PGPUB	2003/
399 BRS 0	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adi transistor)) with beam)) and	USPAT; US-PGPUB	2003/
	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adi transistor)) with beam)) and		2003/
401 BRS 9	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and		2003/
	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and		2003/
	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and		2003/
	((((@ad<20010102) or (@rlad<20010102)) and (array with (photo\$1transistor or (photo adi transistor)))) an		2003/
	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adi transistor)) with beam)) and		2003/
406 BRS 1	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	USPAT; US-PGPUB	2003/
407 BRS 0	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adi transistor)) with beam)) and	USPAT; US-PGPUB	2003/
408 BRS 1	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	USPAT; US-PGPUB	2003/
1409 BRS 0	((photo\$1transistor or (photo adj transistor)) with (flexible adj substrate)) ((photo\$1transistor or (photo adj transistor)) same (flexible adj substrate))	USPAT; US-PGPUB	2003/
410 BRS 1	((photo\$1transistor or (photo adj transistor)) same (flexible adj substrate))	USPAT; US-PGPUB	2003/
411 BRS 0	(((((@ad<20010102)) or (@dad<20010102)) and (array with (photo\$1transistor or (photo adi transistor)))) an	USPAT: US-PGPUB	2003/
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Type Hits	Search Text		DBs	Jime
	((((@ad<20010102) or (@rlad<20010102)) and (array with (photo\$1transistor or (photo adj transistor)))) an			2003/
412 BRS 0	((((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor))) and (@ad<2001010	USPAT; L	JS-PGPUB	2003/
	: ((((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor))) and (@ad<2001010	USPAT; L	JS-PGPUB	2003/
CONTRACTOR CONTRACTOR CONTRACTOR	((((photo\$1transistor or (photo adi transistor)) with ((position or motion) adi sensor))) and (@ad<2001010			2003/
	(US-5986206-\$ or US-6512172-\$ or US-6429040-\$ or US-5670791-\$ or US-5347144-\$ or US-6197663-\$ or U			2004/
	(US-5986206-\$ or US-6512172-\$ or US-6429040-\$ or US-5670791-\$ or US-5347144-\$ or US-6197663-\$ or U			2004/
HATZ BKS 10	"3-octylthiophene" and (photo\$1sensitive or photo\$1sensitivity) "3-octylthiophene" and ((US-5986206-\$ or US-6512172-\$ or US-6429040-\$ or US-5670791-\$ or US-5347144-	USPAT, U	JS-PGPUB	2004/
418 BRS 3 419 BRS 1	: 3-octy(mipphene and ((US-390200-\$ 0) US-031217-\$ 0) US-0429040-\$ 0) US-3670791-\$ 0) US-3547144-	USPAT, U	IS DODIE	2004/
420 BRS 1	:("3-octylthiophene" same (transistor or mosfet or misfet or fet)) - 20020084504	LICEAT I	IS DODIE	2004/
421 BRS 0	*20020084504* *2002(0084504*	LISPAT: I	IS-PGPUB	2004/
422 BRS 4	"2002/0084504" ("3-octylthiophene" and (transistor or mosfet or misfet or fet).ab.)	LISPAT: I	IS-PGPUB	2004/
423 BRS 8	("p3ot" and (transistor or mosfet or misfet or fet))	LISPAT	JS-PGPUB	2004/
424 BRS 3	(("p3ot" and (transistor or mosfet or misfet or fet))) not (("3-octylthiophene" and (transistor or mosfet or misfet			2004/
1425 BRS 20	:("3-octylthiophene" and (transistor or mosfet or misfet or fet))	USPAT: L	JS-PGPUB	2004/
426 BRS 12	("3-octylthiophene" or "p3ot") and tft (("3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and tft) not (("3-octylthiophene" or " Cartylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and tft) not (("3-octylthiophene" or "	USPAT: U	JS-PGPUB	2004/
427 BRS 7	:(("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and tft) not (("3-octylthiophene" or "	USPAT: U	JS-PGPUB	2004/
428 BRS 0	*Poly(3-octy/thiophene-2,5 diyl)*	USPAT: l	JS-PGPUB	2004/
429 BRS 2	:((("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and tft) not (("3-octylthiophene" or "	USPAT; l	JS-PGPUB	2004/
430 BRS 18	:(("3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and (tft or (((thin adj film) or thin\$1fi	USPAT: (JS-PGPUB	2004/
431 BRS 0	("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and (tft or (((thin adi film) or thin\$1fil	EPO; JPO	D; DERWENT	: IBM 2004/
432 BRS 1			JS-PGPUB	2004/
	("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and (tft or (((thin adi film) or thin\$1fil			2004/
	(("3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene or (poly adj octyl adj thiophene) or (p			2004/
	((((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor))) and (@ad<2001010			2004/
436 BRS 1	((((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor))) and (@ad<200101			2004/
	(((((photo\$1transistor or (photo adj transistor)) same ((position or motion) adj sensor))) and (@ad<20010			2004/
438 BRS 1	((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor)) and (((photo\$1transist			2004/
439 BRS 4 440 BRS 14	((photo\$1transistor or (photo adj transistor)) same ((position or motion) adj sensor)) and (((photo\$1transi			2004/
441 BRS 22	((photo\$1transistor or (photo adj transistor)) with imager) and (@ad<20010102 or @rlad<20010102)	USPAI, U	JS-PGPUB	2004/
442 BRS 17	semiconductor and (lexible with imager) and (Mad-20010102 or Mrad-20010102)	USPAI, U	IS DODIE	2004/
443 BRS 2	semiconductor and (flexible with imager) (semiconductor and (flexible with imager)) and (@ad<20010102 or @rlad<20010102) (brittle same_imager) and (@ad<20010102 or @rlad<20010102)	LICDAT: I	IS DODIE	2004/
	(stress with imager) and (@ad<20010102 or @rlad<20010102)	LISPAT: I	IS-PGPUR	2004/
445 BRS 4	(flexible adj substrate) same imager) and (@ad<20010102 or @rlad<20010102)	USPAT: I	IS-PGPUR	2004/
446 BRS 7	((flexible adj substrate)and (imager.ab.)) and (@ad<20010102 or @rlad<20010102)	USPAT I	JS-PGPUB	2004/
447 BRS 6	(cmos adj imager) and (@ad<20010102 or @rlad<20010102) and (economical with (manufacturing or proc	USPAT I	JS-PGPUB	2004/
	(cmos adi image) and (@ad<20010102 or @rlad<20010102) and (economical with (manufacturing or proce			2004/0
449 BRS 1			JS-PGPUB	2004/0
			JS-PGPUB	2004/0
	(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) and ((organic	USPAT: L	JS-PGPUB	2004/0
452 BRS 6	("p3ot" or "p3of" or (octyl adi thiopene)) and tft	USPAT: L	JS-PGPUB	2004/

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